

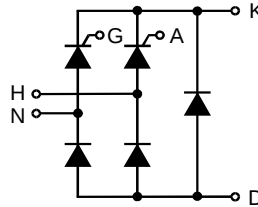
Single Phase Rectifier Bridge

$$I_{dAV} = 32 \text{ A}$$

$$V_{RRM} = 600-1200 \text{ V}$$

Preliminary data

V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V	Type
700	600	VHF 25-06io7
900	800	VHF 25-08io7
1300	1200	VHF 25-12io7



Symbol	Test Conditions		Maximum Ratings	
I_{dAV} ①	$T_C = 85^{\circ}\text{C}$, module		32	A
I_{TAVM}/I_{FAVM}	$T_C = 85^{\circ}\text{C}$; (180° sine ; per thyristor)		16	A
I_{TSM}/I_{FSM}	$T_{VJ} = 45^{\circ}\text{C}$;	$t = 10\text{ ms}$ (50 Hz), sine	200	A
	$V_R = 0$	$t = 8.3\text{ ms}$ (60 Hz), sine	210	A
	$T_{VJ} = T_{VJM}$	$t = 10\text{ ms}$ (50 Hz), sine	180	A
	$V_R = 0$	$t = 8.3\text{ ms}$ (60 Hz), sine	190	A
I^2t	$T_{VJ} = 45^{\circ}\text{C}$	$t = 10\text{ ms}$ (50 Hz), sine	200	A ² s
	$V_R = 0$	$t = 8.3\text{ ms}$ (60 Hz), sine	150	A ² s
	$T_{VJ} = T_{VJM}$	$t = 10\text{ ms}$ (50 Hz), sine	160	A ² s
	$V_R = 0$	$t = 8.3\text{ ms}$ (60 Hz), sine	150	A ² s
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $f = 50\text{ Hz}$, $t_p = 200\text{ }\mu\text{s}$ $V_D = 2/3 V_{DRM}$ $I_G = 0.15\text{ A}$ $di_G/dt = 0.15\text{ A}/\mu\text{s}$	repetitive, $I_T = 20\text{ A}$	100	A/ μs
		non repetitive, $I_T = I_{TAVM}$	500	A/ μs
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$; $R_{GK} = \infty$; method 1 (linear voltage rise)	$V_{DR} = 2/3 V_{DRM}$	500	V/ μs
V_{RGM}			10	V
P_{GM}	$T_{VJ} = T_{VJM}$	$t_p = 30\text{ }\mu\text{s}$	≤ 5	W
	$I_T = I_{TAVM}$	$t_p = 300\text{ }\mu\text{s}$	≤ 2.5	W
P_{GAVM}			0.5	W
T_{VJ}			-40...+125	°C
T_{VJM}			125	°C
T_{stg}			-40...+125	°C
V_{ISOL}	50/60 Hz, RMS	$t = 1\text{ min}$	2500	V~
	$I_{ISOL} \leq 1\text{ mA}$	$t = 1\text{ s}$	3000	V~
M_d	Mounting torque (M4)		1.5 - 2	Nm
			14 - 18	lb.in.
Weight	typ.		18	g

Features

- Package with DCB ceramic base plate
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

Applications

- Supply for DC power equipment
- DC motor control

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight

Data according to IEC 60747 refer to a single diode/thyristor unless otherwise stated

① for resistive load at bridge output. IXYS reserves the right to change limits, test conditions and dimensions.

Dimensions in mm (1 mm = 0.0394")

